DSC5001

Silicon NPN epitaxial planar type

For general amplification Complementary to DSA5001

Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- Eco-friendly Halogen-free package

Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit				
Collector-base voltage (Emitter open)	V _{CBO}	60	V				
Collector-emitter voltage (Base open)	V _{CEO}	50	V				
Emitter-base voltage (Collector open)	V _{EBO}	7	V				
Collector current	I _C	100	mA				
Peak collector current	I _{CP}	200	mA				
Collector power dissipation	P _C	150	mW				
Junction temperature	Tj	150	°C				
Storage temperature	T _{stg}	-55 to +150	°C				

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$	60			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 {\rm mA}, I_{\rm B} = 0$	50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu {\rm A}, I_{\rm C} = 0$	7			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 \text{ V}, I_{B} = 0$			100	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$	210		460	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 10 \text{ mA}$		0.13	0.3	V
Transition frequency	\mathbf{f}_{T}	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		1.5		pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

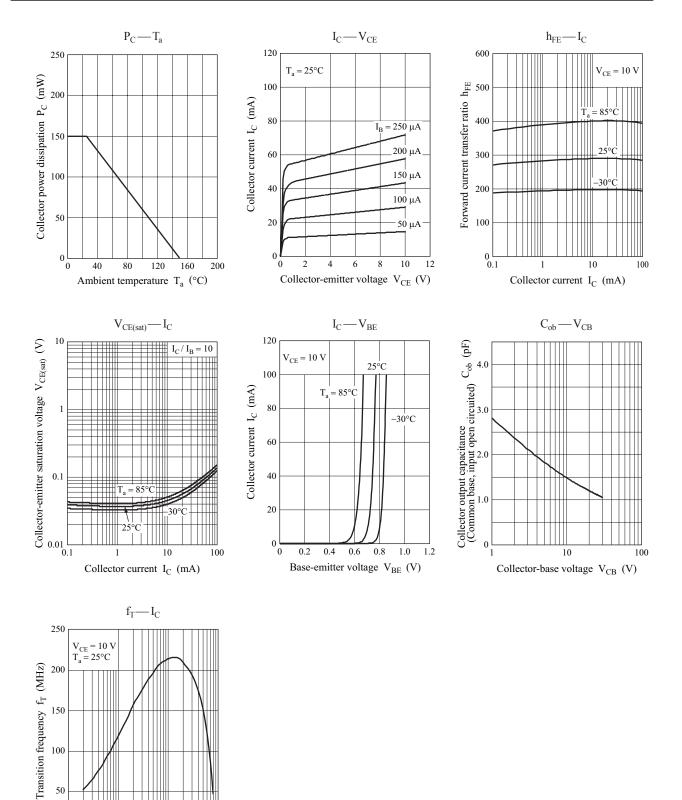
Code	R	S	0	
Rank	R	S	No-rank	
$h_{\rm FE}$	210 to 340	290 to 460	210 to 460	
Marking Symbol	C1R	C1S	C1	

Product of no-rank is not classified and have no marking symbol for rank.

- Package
- Code
- SMini3-F2-B • Pin Name
 - 1. Base
 - 1. Base
 - 2. Emitter
 3. Collector
- Marking Symbol: C1

DSC5001

Panasonic



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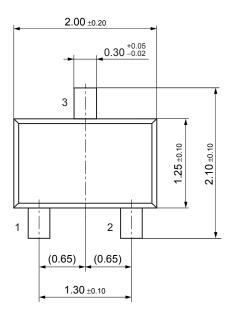
Collector current I_C (mA)

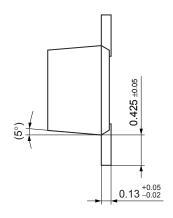
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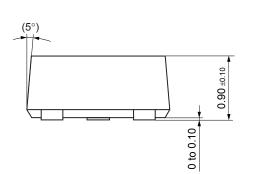
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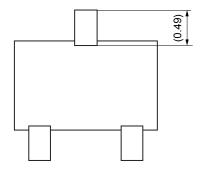
SMini3-F2-B

Unit: mm









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